

Features

- Very low conduction losses
- Negligible switching losses
- Low forward and reverse recovery time
- High junction temperature
- AEC-Q101 qualified

Description

The STTH802-Y uses ST's new 200 V planar Pt doping technology, and is specially suited for switching mode base drive and transistor circuits.

Packaged in DPAK, this device is intended for use in low voltage, high frequency inverters, free wheeling and polarity protection for automotive application.

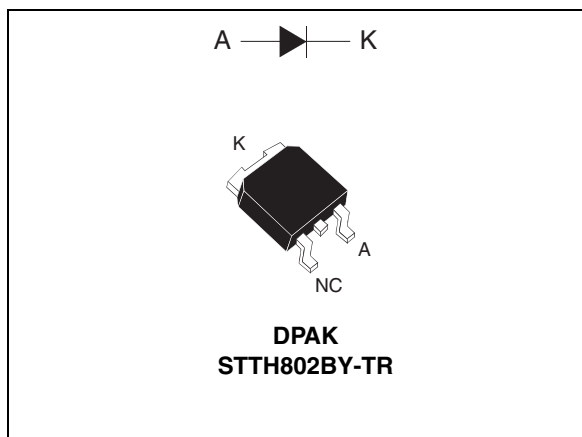


Table 1. Device summary

$I_{F(AV)}$	8 A
V_{RRM}	200 V
$T_j (max)$	175 °C
$V_F (typ)$	0.8 V
$t_{rr} (typ)$	17 ns

1 Characteristics

Table 2. Absolute ratings (limiting values at $T_j = 25\text{ °C}$, unless otherwise specified)

Symbol	Parameter	Value	Unit
V_{RRM}	Repetitive peak reverse voltage	200	V
$I_{F(RMS)}$	Forward rms current	16	A
$I_{F(AV)}$	Average forward current, $\delta = 0.5$	$T_c = 145\text{ °C}$	A
I_{FSM}	Surge non repetitive forward current	$t_p = 10\text{ ms}$ sinusoidal	A
T_{stg}	Storage temperature range	-65 to + 175	°C
T_j	Operating junction temperature range	-40 to + 175	°C

Table 3. Thermal parameters

Symbol	Parameter	Value	Unit
$R_{th(j-c)}$	Junction to case	3.2	°C/W

Table 4. Static electrical characteristics

Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
$I_R^{(1)}$	Reverse leakage current	$T_j = 25\text{ °C}$	$V_R = V_{RRM}$		6	μA
		$T_j = 125\text{ °C}$		6	60	
$V_F^{(2)}$	Forward voltage drop	$T_j = 25\text{ °C}$	$I_F = 8\text{ A}$	0.95	1.05	V
		$T_j = 150\text{ °C}$		0.8	0.90	

1. Pulse test: $t_p = 5\text{ ms}$, $\delta < 2\%$

2. Pulse test: $t_p = 380\text{ }\mu\text{s}$, $\delta < 2\%$

To evaluate the conduction losses use the following equation:

$$P = 0.73 \times I_{F(AV)} + 0.021 I_{F(RMS)}^2$$

Table 5. Dynamic characteristics

Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
t_{rr}	Reverse recovery time	$I_F = 1\text{ A}$, $dI_F/dt = -50\text{ A}/\mu\text{s}$, $V_R = 30\text{ V}$, $T_j = 25\text{ °C}$		25	30	ns
		$I_F = 1\text{ A}$, $dI_F/dt = -100\text{ A}/\mu\text{s}$, $V_R = 30\text{ V}$, $T_j = 25\text{ °C}$		17	22	
I_{RM}	Reverse recovery current	$I_F = 8\text{ A}$, $dI_F/dt = -200\text{ A}/\mu\text{s}$, $V_R = 160\text{ V}$, $T_j = 125\text{ °C}$		5.5	7	A
t_{fr}	Forward recovery time	$I_F = 8\text{ A}$, $dI_F/dt = 50\text{ A}/\mu\text{s}$ $V_{FR} = 1.1 \times V_{Fmax}$, $T_j = 25\text{ °C}$		150		ns
V_{FP}	Forward recovery voltage	$I_F = 8\text{ A}$, $dI_F/dt = 50\text{ A}/\mu\text{s}$, $T_j = 25\text{ °C}$		1.5		V

Figure 1. Peak current versus duty cycle

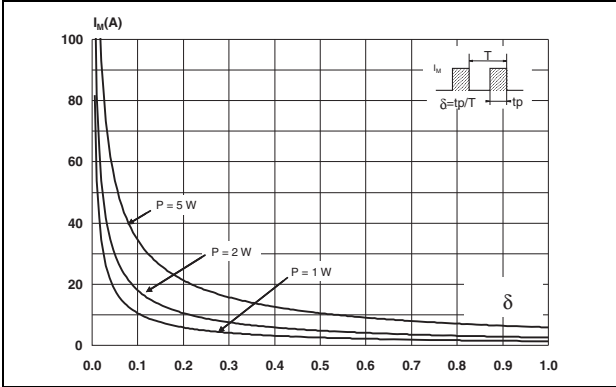


Figure 2. Forward voltage drop versus forward current (typical values)

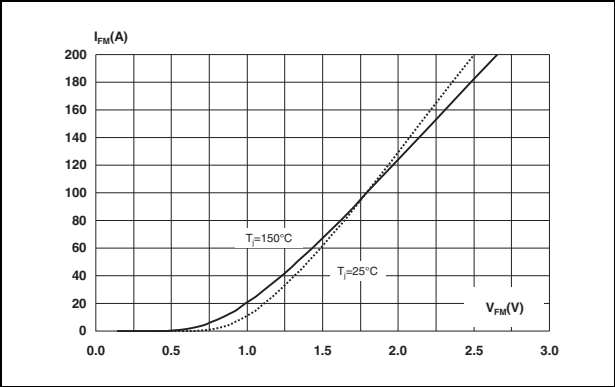


Figure 3. Forward voltage drop versus forward current (maximum values)

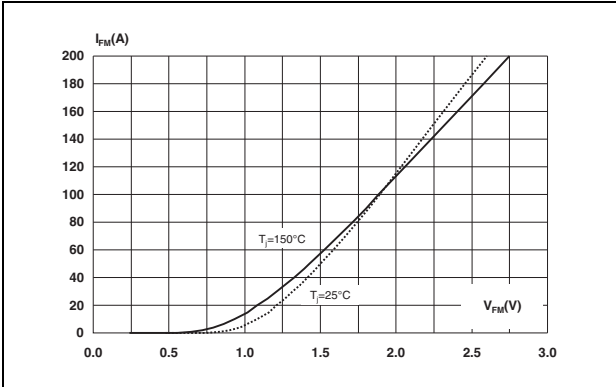


Figure 4. Relative variation of thermal impedance, junction to case, versus pulse duration

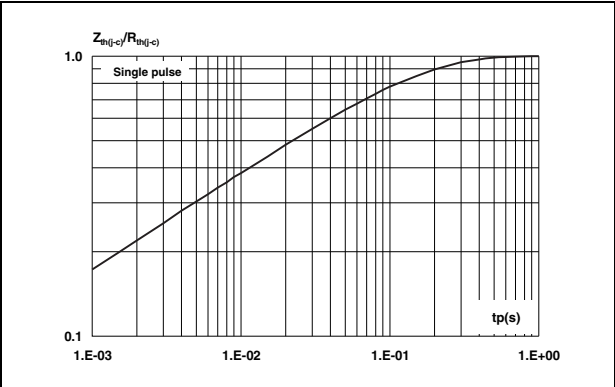


Figure 5. Junction capacitance versus reverse applied voltage (typical values)

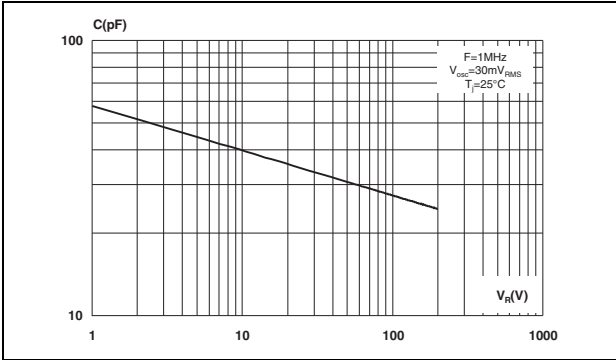
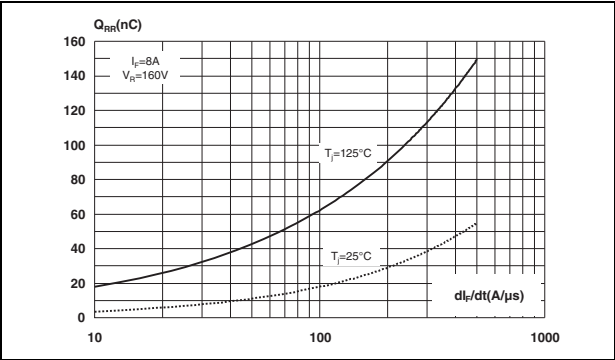


Figure 6. Reverse recovery charges versus dI_F/dt (typical values)



3 Ordering information

Table 7. Ordering information

Order code	Marking	Package	Weight	Base qty	Delivery mode
STTH802BY-TR	STTH802Y	DPAK	0.3 g	2500	Tape and reel